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2STC5948

High power NPN epitaxial planar bipolar transistor

Features

- High breakdown voltage V_{CEO} = 250 V
- Complementary to 2STA2120
- Typical f_t = 25 MHz
- Fully characterized at 125 °C

Application

Audio power amplifier

Description

The device is a NPN transistor manufactured using new BiT-LA (Bipolar transistor for linear amplifier) technology. The resulting transistor shows good gain linearity behaviour. bsolete Productle

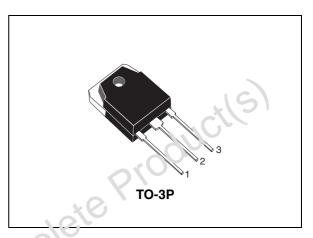


Figure 1. Internal schematic diagram

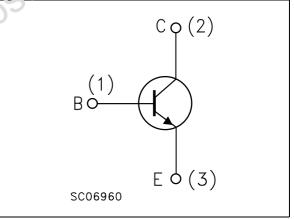


Table 1. Device summa

Order code	Marking	Package	Packaging	
2STC5948	2STC5948	TO-3P	Tube	

Electrical ratings 1

Table 2. Absolute maximum rating

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-base voltage $(I_E = 0)$	250	V
V _{CEO}	Collector-emitter voltage $(I_B = 0)$	250	V
V _{EBO}	Emitter-base voltage ($I_{C} = 0$)	6	V
۱ _C	Collector current	17	Α
I _{CM}	Collector peak current (t _P < 5 ms)	34	Α
P _{TOT}	Total dissipation at $T_c = 25 \ ^{\circ}C$	200	W
T _{stg}	Storage temperature	-65 to 150	0.0
Т _Ј	Max. operating junction temperature	150	°C
Table 3. Thermal data			
-			

Table 3. Thermal data

	Symbol	Parameter	R	Value	Unit
	R _{thj-case}	Thermal resistance junction-case	r.a.	0.625	°C/W
		oducits		0.020	
obsole	teP	;0 ⁰ °			

2 Electrical characteristics

($T_{case} = 25 \ ^{\circ}C$; unless otherwise specified)

Table 4.	Electrical	characteristics

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I _{CBO}	Collector cut-off current (I _E = 0)	V _{CB} = 250 V			5	μA
I _{EBO}	Emitter cut-off current (I _C = 0)	V _{EB} = 6 V			5	μA
V _{(BR)CEO} ⁽¹⁾	Collector-emitter breakdown voltage (I _B = 0)	I _C = 50 mA	250			v
V _{(BR)CBO}	Collector-base breakdown voltage ($I_{F} = 0$)	I _C = 100 μΑ	250	50		V
V _{(BR)EBO} ⁽¹⁾	Emitter-base breakdown voltage (I _C = 0)	I _E = 1 mA	3			V
V _{CE(sat)} ⁽¹⁾	Collector-emitter saturation voltage	I _C = 8 A I _B = 8 ໃບ mA			3	V
V _{BE} ⁽¹⁾	Base-emitter voltage	$I_{\rm C} = 7 {\rm A}$ $V_{\rm CE} = 5 {\rm V}$			1.5	V
h _{FE}		I _C = 1 A. V _{CE} = 5 V	80		160	
"FE	Do ourroin gain	$V_{CE} = 5 V$	35			
f _T	Transition frequency	$I_{\rm C} = 1 {\rm A}$ $V_{\rm CE} = 5 {\rm V}$		25		MHz

1. Pulsed duration = 300 μs, duty cycle ≤ 1.5%

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2.1 Electrical characteristics (curves)

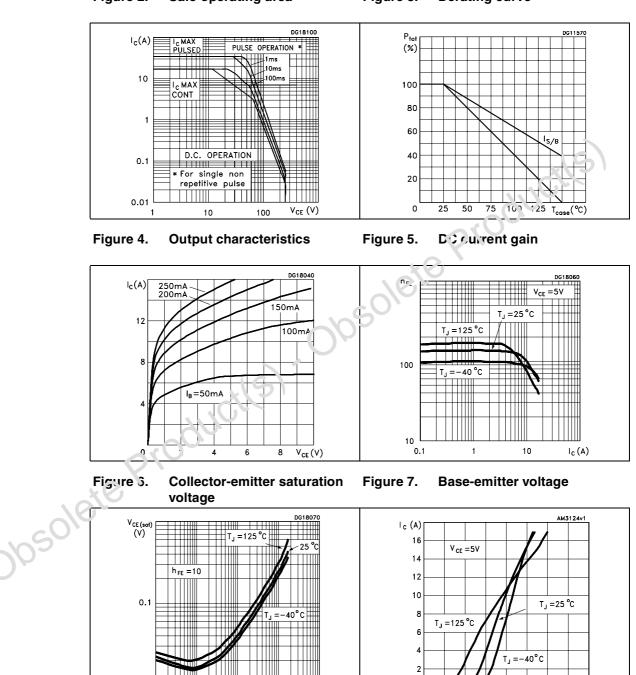


Figure 2. Safe operating area

Figure 3. Derating curve

0.2 0.4 0.6 0.8

1

1.2 1.4 V_{BE} (V)

0.01

0.01

0.1

1

10

I_c (A)

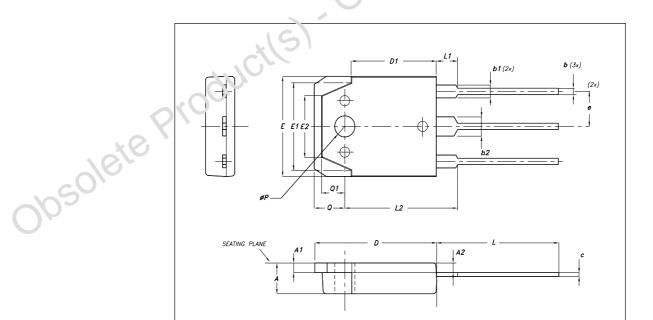
3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

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TO-3P Mechanical data			
DIM.		mm.	
	MIN.	ТҮР	MAX.
A	4.6		5
A1	1.45	1.50	1.65
A2	1.20	1.40	1.60
b	0.80	1	1.20
b1	1.80		2.20
b2	2.80		3.20
с	0.55	0.60	0.75
D	19.70	19.90	20.1
D1		13.90	
E	15.40		15.d0
E1		13.60	10
E2		9.60	
е	5.15	5.45	5.75
L	19.50	20	20.50
L1		3 50	
L2	18.20	1 7.40	18.60
Р	3.10		3.30
Q		5	
Q1		3.80	





4 Revision history

Table 5. Document revision history

	Date	Revision	Changes
	26-Nov-2007	1	Initial release.
	06-May-2008	2	New graphics
	11-Jul-2008	3	Updated Figure 7.
	17-Nov-2008	4	Content reworked to improve readability, no technical changes
obsole	teptod		Content reworked to improve readability, no technical changes

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